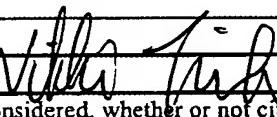


<b>INFORMATION DISCLOSURE CITATION FORM FOR PATENT APPLICATION (FORM PTO-1449)</b> (Substitute)		Docket No.02W155	Serial No.:			
		Applicant(s): Kennedy et al.				
		Filing Date: Herewith	Group:			
<b>U.S. PATENT DOCUMENTS</b>						
Examiner Initials	Document Number (Number-Kind Code)	Publication Date (MM-DD-YYYY)	Name of Patentee or Applicant	Class	Sub-class	
	US-6,326,611	12-04-2001	Kennedy et al.	250	239	
	US-6,122,919	09-26-2000	Patel et al.	62	51.1	
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<b>FOREIGN PATENT DOCUMENTS</b>						
Examiner Initials	Document Number (Country Code-Number-Kind Code)	Publication Date (MM-DD-YYYY)	Name Of Patentee of Applicant	Translation? Yes/No/n/a		
<b>OTHER DOCUMENTS (Author (Capitalize), Title, Date, Pages, Etc., if known)</b>						
"Fluxless High-Vacuum Packaging of MEMS and IR Sensors", SST International, September 2002.						
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Examiner's Signature: 		Date Considered: 8/18/05				
Initial if reference was considered, whether or not citation is in conformance with MPEP. Mark through citation if not considered. Include a copy of this citation form with your next correspondence to the Applicant(s).						